



DMP22M2UPS

Product Summary

BV _{DSS}	R _{DS(ON)} max	Ι _D T _C = +25°C
-20V	2.5mΩ @ V _{GS} = -10V	-60A
	3.5mΩ @ V _{GS} = -4.5V	-60A

Description

This new generation P-Channel Enhancement Mode MOSFET is designed to minimize $R_{\text{DS}(\text{ON})}$ and yet maintain superior switching performance.

Applications

- Load Switch
- Notebook Battery Power Management

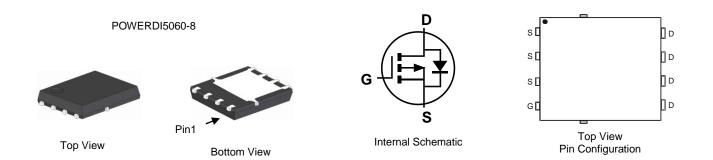
20V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI[®]

Features

- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: POWERDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMP22M2UPS-13	POWERDI5060-8	2,500 / Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

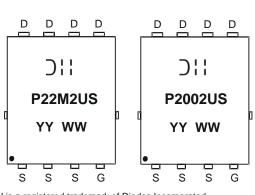
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



POWERDI5060-8

 \bigcirc **! !** = Manufacturer's Marking P22M2US or P2002US = Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 14 = 2014) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-20	V		
Gate-Source Voltage	V _{GSS}	±12	V		
	Steady State (Note 6)	T _C = +25°C T _C = +70°C		-60 -60	A
Continuous Drain Current, V _{GS} = 10V (Note 5)	t<10s	T _A = +25°C T _A = +70°C	١D	-42 -33.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-100	А		
Continuous Body Diode Forward Current (Note 5)	Steady State (Note 6)	T _C = +25°C	- Is	-60	А
	t<10s	T _A = +25°C	15	-5.6	A
Avalanche Current, L = 0.1mH	I _{AS}	-37	А		
Avalanche Energy, L = 0.1mH			E _{AS}	69.8	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Units	
Total Dowar Dissinction (Nota E)	Steady State		2.3	w
Total Power Dissipation (Note 5)	t<10s	P _D	6.25	
Thermal Decistorian Lunction to Ambient (Note 5)	Steady State	P	55	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	R _{θJA}	20	
Total Power Dissipation (Note 5)	Steady State	PD	104	W
Thermal Resistance, Junction to Case (Note 5)		R _{ejc}	0.9	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

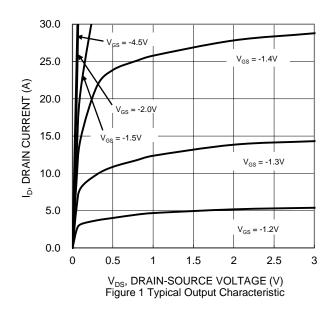
Note: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate. 6. Package limited.

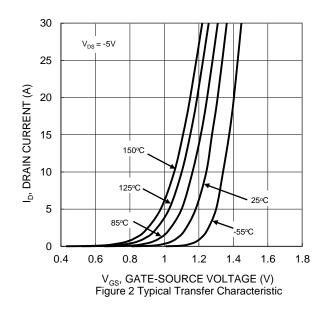


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}			-10	μA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-0.5	_	-1.4	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
		_	-	2.5		V _{GS} = -10V, I _D = -25A	
Static Drain-Source On-Resistance	R _{DS(ON)}		—	3.5	mΩ	V _{GS} = -4.5V, I _D = -20A	
			—	5.0		V _{GS} = -2.5V, I _D = -15A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		12826				
Output Capacitance	Coss		2547	_	pF	$V_{DS} = -10V, V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	_	1924	_			
Gate Resistance	R _G	_	4.2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -10V)	Qg	—	476	—		V _{DS} = -10V, I _D = -20A	
Total Gate Charge (V _{GS} = -4.5V)	Qg	—	228	—	nC		
Gate-Source Charge	Q _{gs}	—	24.8	—	nc		
Gate-Drain Charge	Q _{gd}	_	61.9	—			
Turn-On Delay Time	t _{D(ON)}	—	14.2	—			
Turn-On Rise Time	t _R	_	35.4	_		$V_{DD} = -10V, V_{GEN} = -4.5V,$ $R_{GEN} = 1\Omega, I_D = -10A$	
Turn-Off Delay Time	t _{D(OFF)}	—	361	—	ns		
Turn-Off Fall Time	t _F	_	224	—			
BODY DIODE CHARACTERISTICS							
Diode Forward Voltage	V _{SD}		-0.58		V	$V_{GS} = 0V, I_{S} = -5A$	
Reverse Recovery Time (Note 8)	t _{RR}		137	_	ns		
Reverse Recovery Charge (Note 8)	Qrr		221		nC		
Reverse Recovery Fall Time (Note 8)	ta		39	_		I _F = -10A, di/dt = 100A/µs	
Reverse Recovery Raise Time (Note 8)	t _b	_	98		ns		

Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.





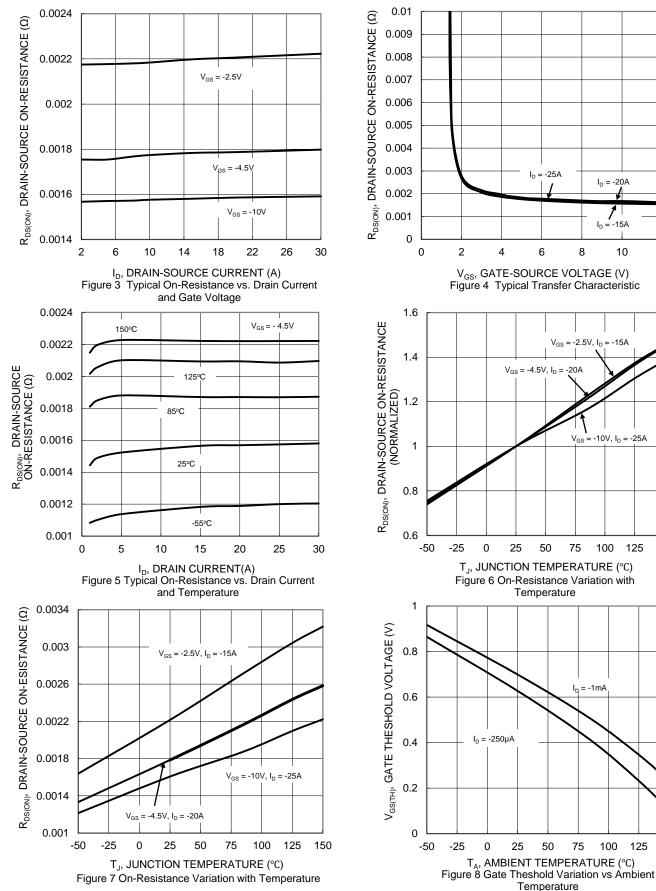
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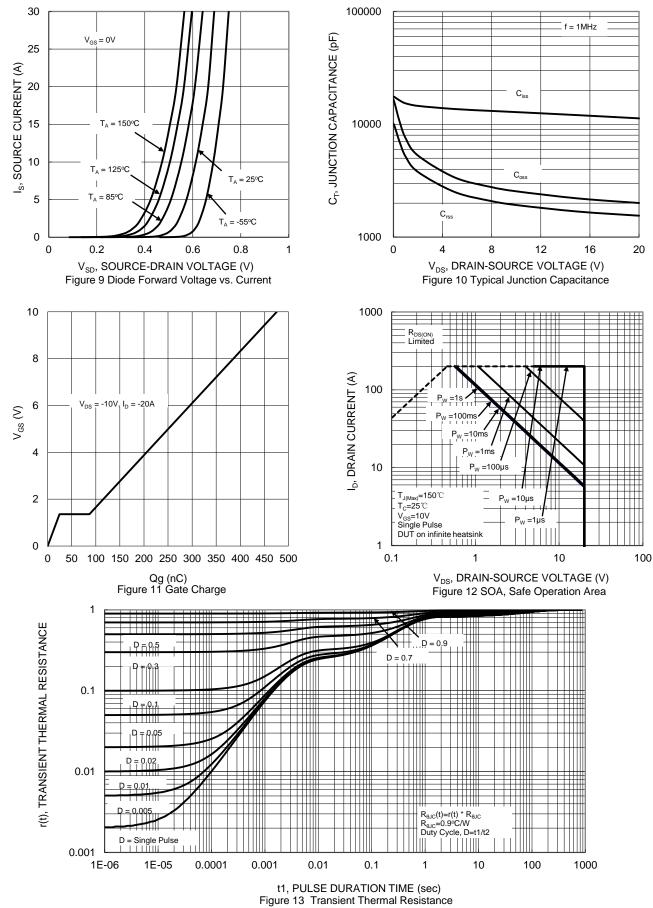


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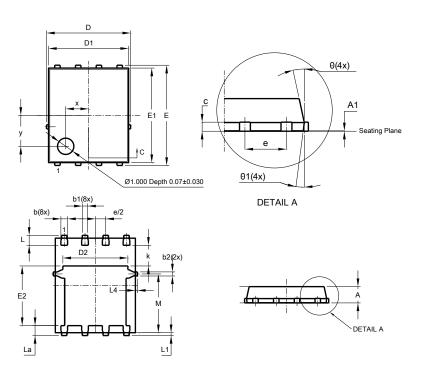


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Package Outline Dimensions

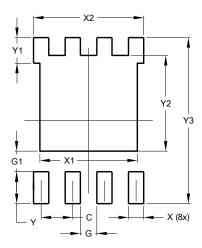
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	PowerDI5060-8					
(Type K)						
Dim	Min Max		Тур			
Α	0.90	1.10	1.00			
A1	0	0.05	0.02			
b	0.33	0.51	0.41			
b1	0.300	0.366	0.333			
b2	0.20	0.35	0.25			
С	0.23	0.33	0.277			
D	5	.15 BS0	0			
D1	4.85	4.95	4.90			
D2	3.98					
E	6.15 BSC					
E1	5.75	5.85	5.80			
E2	3.56	3.76	3.66			
E	1	.27BSC	~			
k	-	-	1.27			
L	0.51	0.71	0.61			
La	0.51	0.71	0.61			
L1	0.05	0.20	0.175			
L4	-	-	0.125			
М	3.50	3.71	3.605			
х	-	-	1.400			
У	-	-	1.900			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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